PHOTON IS OUR BUSINESS

# Si PIN photodiodes



S2506 series S6775 series S6967

## Plastic SIP (single in-line package)

S2506/S6775 series and S6967 are Si PIN photodiodes with large active areas, molded into a clear or visible-cut plastic SIP for detecting visible to near infrared range or near infrared range only. These Si PIN photodiodes feature a high sensitivity, a highspeed response and large active areas.

#### Features

**■ S2506-02: Visible to near infrared range** 

S2506-04: Visible-cut

S6775, S6967: Visible to near infrared range, high sensitivity,

high-speed response, large active area

S6775-01: Visible-cut, high sensitivity,

high-speed response, large active area

→ Plastic package: 7 × 7.8 mm

Photosensitive area size

S2506 series: 2.77 × 2.77 mm S6775 series, S6967: 5.5 × 4.8 mm

#### Applications

- **→** FSO (free space optics)
- Optical switches
- → Laser radar, etc.

#### **其** General ratings / Absolute maximum ratings

	Package	Photosensitive area size	Effective	Absolute maximum ratings					
Type no.			photosensitive area	Reverse voltage VR max.	Power dissipation P	Operating temperature Topr	Storage temperature Tstg		
		(mm)	(mm²)	(V)	(mW)	(°C)	(°C)		
S2506-02		2.77 × 2.77	7.7		150		-40 to +100		
S2506-04		2.// ^ 2.//	7.7		150				
S6775	Plastic			35		-25 to +85			
S6775-01		5.5 × 4.8	26.4		50				
S6967									

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

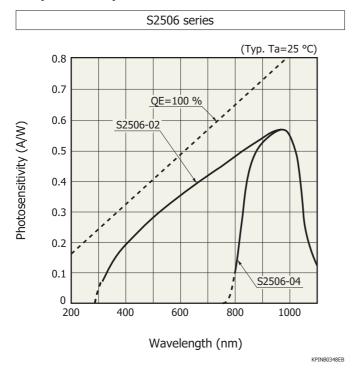
#### **■** Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

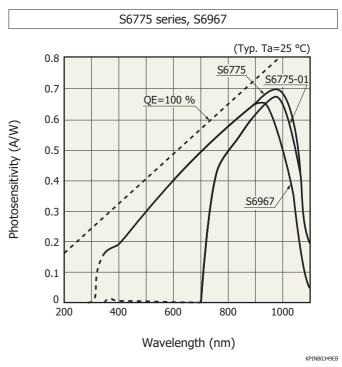
Timo no	Spectral response range	Peak sensitivity wavelength λp	Photosensitivity S (A/W)			Short circuit current	Dark current		Temp. coefficient of	Cut-off frequency fc Ct Terminal capacitance		NEP	
Type no.							Isc			ID	RL=50 Ω	f=1 MHz	
		ļ .	λр	660 nm	780 nm	830 nm	100 <i>lx</i>	Тур.	Max.	TCID	-3 dB		
	(nm)	(nm)					(µA)	(nA)	(nA)	(times/°C)	(MHz)	(pF)	(W/Hz <sup>1/2</sup> )
S2506-02	320 to 1100	960	0.56	0.4	0.48	0.5	7.3	0.1*1	10* <sup>1</sup>		25*¹	15* <sup>1</sup>	1.0 × 10 <sup>-14*1</sup>
S2506-04	760 to 1100	900	0.50	-	-	0.25	4.1	0.1	10 1		25 -		1.0 × 10
S6775	320 to 1100	960	0.7	0.45	0.55	0.6	30	0.5*2	0.5*2 10*2	1.15	15* <sup>2</sup>	40^2	1.8 × 10 <sup>-14*2</sup>
S6775-01	700 to 1100		0.68	-	0.48	0.54	21						$1.9 \times 10^{-14*2}$
S6967	320 to 1060	900	0.65	0.45	0.55	0.6	26		5* <sup>2</sup>		50* <sup>2</sup>	50* <sup>2</sup>	2.0 × 10 <sup>-14*2</sup>

<sup>\*1:</sup> VR=12 V

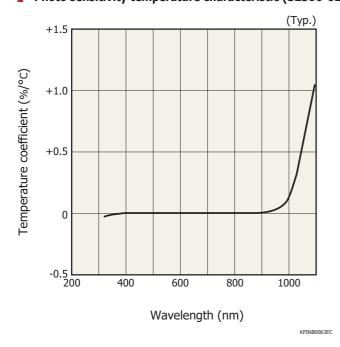
<sup>\*2:</sup> VR=10 V

#### Spectral response

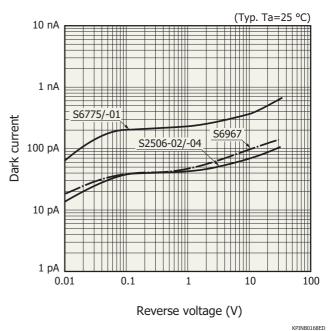




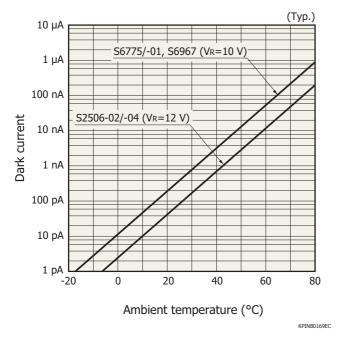
#### Photo sensitivity temperature characteristic (\$2506-02)



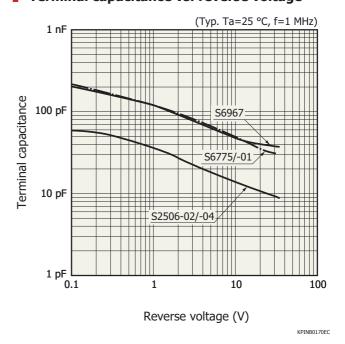
#### Dark current vs. reverse voltage



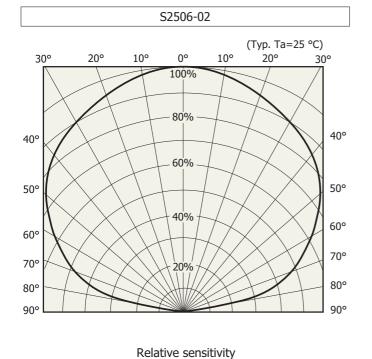
#### Dark current vs. ambient temperature



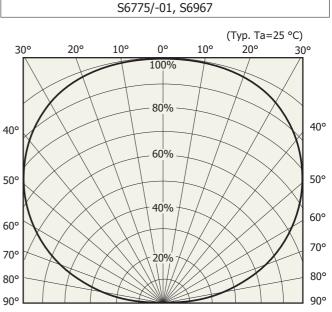
### **▶** Terminal capacitance vs. reverse voltage



#### Directivity



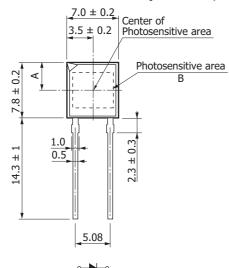


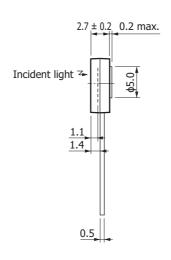


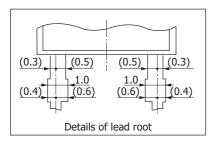
Relative sensitivity

KPINB0401EA

#### Dimensional outline (unit: mm, tolerance unless otherwise noted: ±0.1)







Type no.	Α	В		
S2506 series	$2.8 \pm 0.2$	2.77 × 2.77		
S6775/series S6967	3.65 ± 0.2	5.5 × 4.8		

Lead surface finish: Silver plating Packing: Polyethylene pack [anti-static type] (200 pcs/pack)

KPINA0084ED

#### Si PIN photodiodes

#### S2506/S6775 series, S6967

#### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
  - Notice
  - · Metal, ceramic, plastic package products
- Technical information
  - · Si photodiode/Application circuit examples

Information described in this material is current as of November, 2014.

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The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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